# onsemi

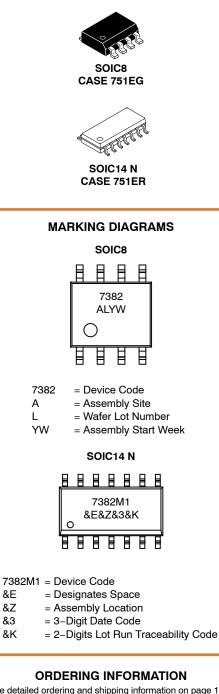
## **High-Side and Low-Side Gate Driver**

## **FAN7382**

The FAN7382, a monolithic high and low side gate-drive IC, can drive MOSFETs and IGBTs that operate up to +600 V. onsemi's high-voltage process and commonmode noise canceling technique provides stable operation of the high-side driver under high-dv/dt noise circumstances. An advanced level-shift circuit allows high-side gate driver operation up to  $V_S = -9.8$  V (typical) for  $V_{BS} = 15$  V. The input logic level is compatible with standard TTL-series logic gates. UVLO circuits for both channels prevent malfunction when V<sub>CC</sub> or V<sub>BS</sub> is lower than the specified threshold voltage. Output drivers typically source/sink 350 mA/650 mA, respectively, which is suitable for fluorescent lamp ballasts, PDP scan drivers, motor controls, etc.

#### Features

- Floating Channels Designed for Bootstrap Operation to +600 V
- Typically 350 mA/650 mA Sourcing/Sinking Current Driving Capability for Both Channels
- Common-Mode dv/dt Noise Canceling Circuit
- Extended Allowable Negative V<sub>S</sub> Swing to -9.8 V for Signal Propagation at  $V_{CC} = V_{BS} = 15 \text{ V}$
- V<sub>CC</sub> & V<sub>BS</sub> Supply Range from 10 V to 20 V
- UVLO Functions for Both Channels
- TTL Compatible Input Logic Threshold Levels
- Matched Propagation Delay Below 50 ns
- Output In-phase with Input Signal
- These are Pb-Free Devices



See detailed ordering and shipping information on page 12 of this data sheet.

&Z

&3

&K

#### **Typical Application Circuit**

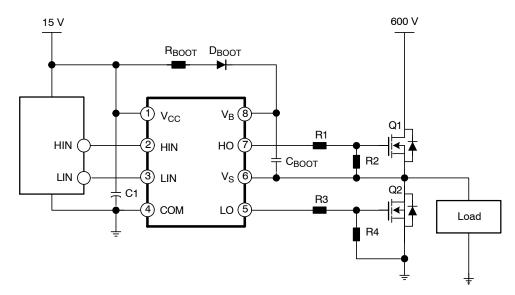
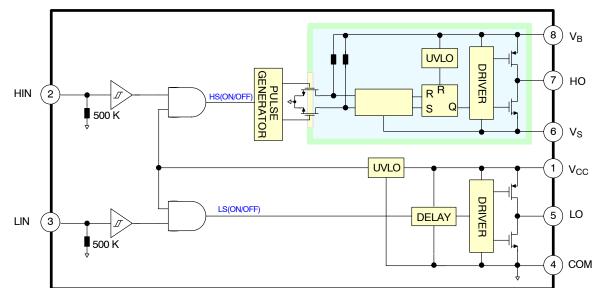


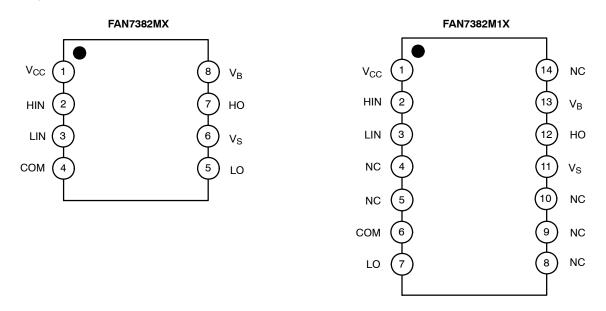
Figure 1. Application Circuit for Half-Bridge



Internal Block Diagram



#### **Pin Assignments**





#### **PIN DIFINITIONS**

Name	Description
V <sub>CC</sub>	Low-Side Supply Voltage
HIN	Logic Input for High-Side Gate Driver Output
LIN	Logic Input for Low-Side Gate Driver Output
СОМ	Logic Ground and Low-Side Driver Return
LO	Low-Side Driver Output
V <sub>S</sub>	High-Voltage Floating Supply Return
НО	High-Side Driver Output
V <sub>B</sub>	High–Side Floating Supply

#### **ABSOLUTE MAXIMUM RATINGS**

Parameter	Symbo	bl	Min	Мах	Unit
High-Side Offset Voltage	V <sub>S</sub>		V <sub>B</sub> – 25	V <sub>B</sub> + 0.3	V
High-Side Floating Supply Voltage	V <sub>B</sub>		-0.3	625	
High-Side Floating Output Voltage HO	V <sub>HO</sub>		V <sub>S</sub> – 0.3	V <sub>B</sub> + 0.3	
Low-Side and Logic Fixed Supply Voltage	V <sub>CC</sub>		-0.3	25	
Low-Side Output Voltage LO	V <sub>LO</sub>		-0.3	V <sub>CC</sub> + 0.3	
Logic Input Voltage (HIN, LIN)	V <sub>IN</sub>		-0.3	V <sub>CC</sub> + 0.3	
Logic Ground	СОМ	`	V <sub>CC</sub> – 25	V <sub>CC</sub> + 0.3	
Allowable Offset Voltage Slew Rate	dV <sub>S</sub> /dt	t		50	V/ns
Power Dissipation	PD		SOIC8	0.625	W
	(Notes 1, 2	2, 3)	SOIC14 N	1.0	
Junction temperature	TJ			150	°C
Storage Temperature	T <sub>STG</sub>			150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. Mounted on  $76.2 \times 114.3 \times 1.6$  mm PCB (FR-4 glass epoxy material).

2. Refer to the following standards:

JESD51–2: Integral circuits thermal test method environmental conditions – natural convection JESD51–3: Low effective thermal conductivity test board for leaded surface mount packages

3. Do not exceed P<sub>D</sub> under any circumstances.

#### THERMAL CHARACTERISTICS

Parameter	Symbol	Min	Max	Unit
Thermal Resistance, Junction-to-Ambient	$\theta_{JA}$	SOIC8	200	°C/W
		SOIC14 N	110	

#### **RECOMMENDED OPERATING CONDITIONS**

Parameter	Symbol	Min	Max	Unit
High-Side Floating Supply Voltage	V <sub>B</sub>	V <sub>S</sub> + 10	V <sub>S</sub> + 20	V
High-Side Floating Supply Offset Voltage	V <sub>S</sub>	6 – V <sub>CC</sub>	600	V
High-Side (HO) Output Voltage	V <sub>HO</sub>	V <sub>S</sub>	VB	V
Low-Side (LO) Output Voltage	V <sub>LO</sub>	COM	V <sub>CC</sub>	V
Logic Input Voltage (HIN, LIN)	V <sub>IN</sub>	COM	V <sub>CC</sub>	V
Low-Side Supply Voltage	V <sub>CC</sub>	10	20	V
Ambient Temperature	T <sub>A</sub>	-40	125	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

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#### **ELECTRICAL CHARACTERISTICS**

 $V_{BIAS}$  ( $V_{CC}$ ,  $V_{BS}$ ) = 15.0 V,  $T_A$  = 25°C, unless otherwise specified. The  $V_{IN}$  and  $I_{IN}$  parameters are referenced to COM. The  $V_O$  and  $I_O$  parameters are referenced to  $V_S$  and COM and are applicable to the respective outputs HO and LO.

Parameter	Test Condition	Symbol	Min	Тур	Max	Unit
$V_{CC}$ and $V_{BS}$ Supply Under–Voltage Positive Going Threshold		V <sub>CCUV+</sub> V <sub>BSUV+</sub>	8.2	9.2	10.0	V
$V_{CC}$ and $V_{BS}$ Supply Under–Voltage Positive Going Threshold		V <sub>CCUV-</sub> V <sub>BSUV-</sub>	7.6	8.7	9.6	V
V <sub>CC</sub> Supply Under-Voltage Lockout Hysteresis		V <sub>CCUVH</sub> V <sub>BSUVH</sub>		0.6		V
Offset Supply Leakage Current	$V_{\rm B} = V_{\rm S} = 600 \ {\rm V}$	I <sub>LK</sub>			50	μA
Quiescent V <sub>BS</sub> Supply Current	V <sub>IN</sub> = 0 V or 5 V	I <sub>QBS</sub>		45	120	μA
Quiescent V <sub>CC</sub> Supply Current	$V_{IN} = 0 V \text{ or } 5 V$	I <sub>QCC</sub>		70	180	μA
Operating V <sub>BS</sub> Supply Current	f <sub>IN</sub> = 20 kHz, rms value	I <sub>PBS</sub>			600	μA
Operating V <sub>CC</sub> Supply Current	f <sub>IN</sub> = 20 kHz, rms value	I <sub>PCC</sub>			600	μA
Logic "1" Input Voltage		V <sub>IH</sub>	2.9			V
Logic "0" input voltage		V <sub>IL</sub>			0.8	V
High-Level Output Voltage, V <sub>BIAS</sub> - V <sub>O</sub>	I <sub>O</sub> = 20 mA	V <sub>OH</sub>			1.0	V
Low-Level Output Voltage, VO		V <sub>OL</sub>			0.6	V
Logic "1" Input Bias Current	V <sub>IN</sub> = 5 V	I <sub>IN+</sub>		10	20	μA
Logic "0" Input Bias Current	V <sub>IN</sub> = 0 V	I <sub>IN-</sub>		1.0	2.0	μA
Output High Short-Circuit Pulsed Current	$\label{eq:VO} \begin{array}{l} V_O = 0 \ V, \ V_{IN} = 5 \ V \\ \text{with PW} < 10 \ \mu s \end{array}$	I <sub>O+</sub>	250	350		mA
Output Low Short-Circuit Pulsed Current	$V_O$ = 15 V, $V_{IN}$ = 0 V with PW < 10 $\mu s$	I <sub>O-</sub>	500	650		mA
Allowable Negative VS Pin Voltage for HIN Signal Propagation to HO		VS		-9.8	-7.0	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

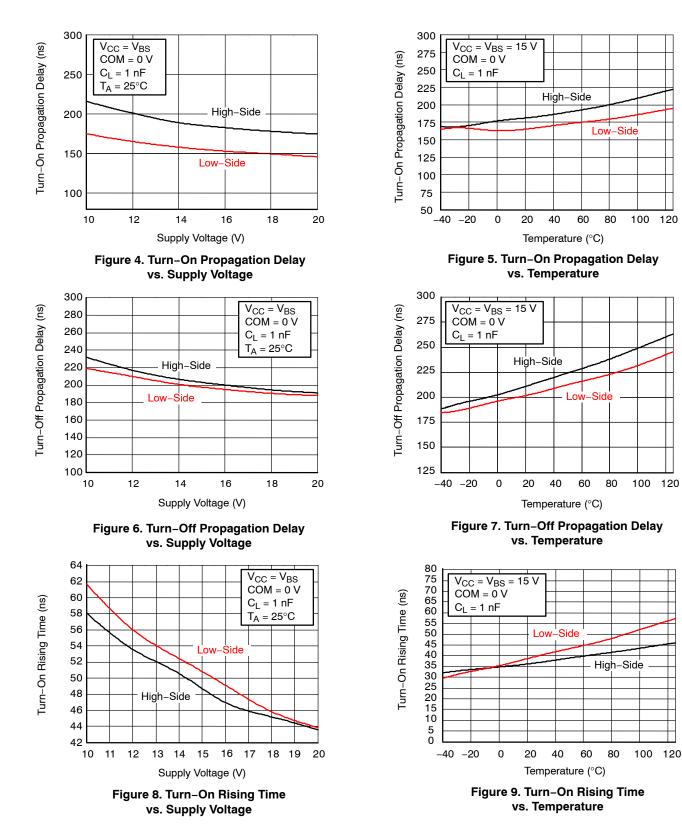
#### DYNAMIC ELECTRICAL CHARACTERISTICS

 $V_{BIAS}~(V_{CC},~V_{BS})$  = 15.0 V,  $V_S$  = COM,  $C_L$  = 1000 pF and,  $T_A$  = 25°C, unless otherwise specified.

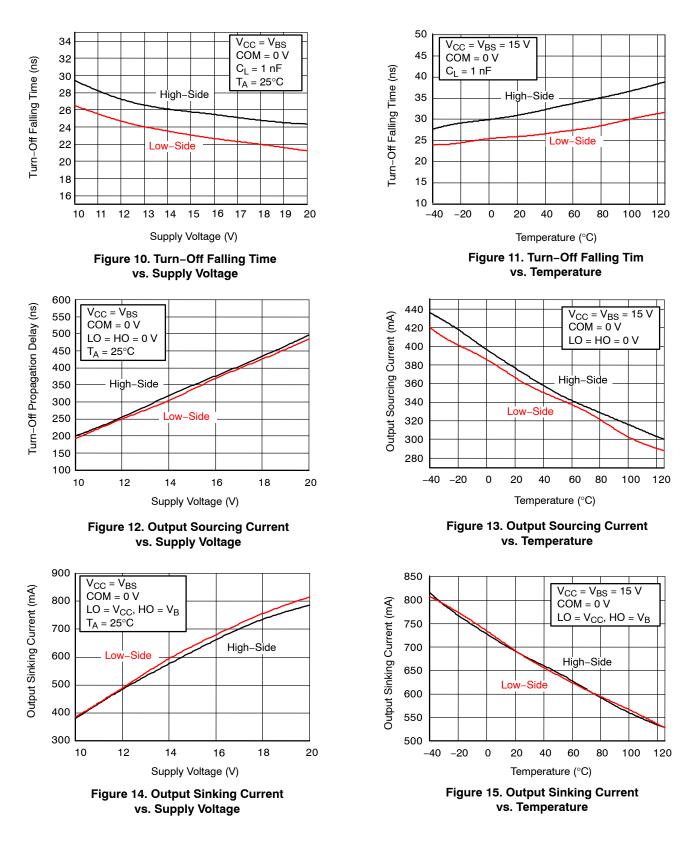
Parameter	Test Condition	Symbol	Min	Тур	Max	Unit
Turn-On Propagation Delay	V <sub>S</sub> = 0 V	t <sub>on</sub>	100	170	300	ns
Turn-Off Propagation Delay	V <sub>S</sub> = 0 V or 600 V (Note 4)	t <sub>off</sub>	100	200	300	ns
Turn-On Rise Time		t <sub>r</sub>	20	60	140	ns
Turn-Off Fall Time		t <sub>f</sub>		30	80	ns
Delay Matching, HS & LS Turn-On/Off		MT			50	ns

4. This parameter guaranteed by design.

#### **TYPICAL CHARACTERISTICS**

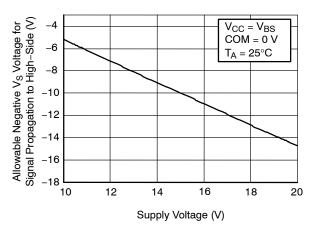


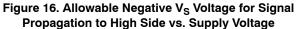
#### TYPICAL CHARACTERISTICS (continued)



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#### TYPICAL CHARACTERISTICS (continued)





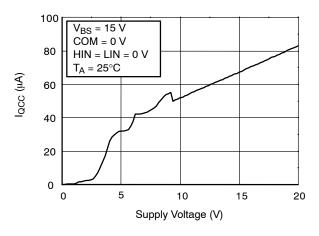


Figure 18. I<sub>QCC</sub> vs. Supply Voltage

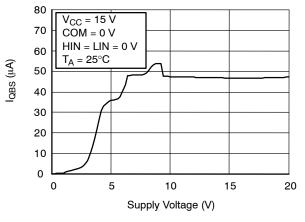


Figure 20. I<sub>QBS</sub> vs. Supply Voltage

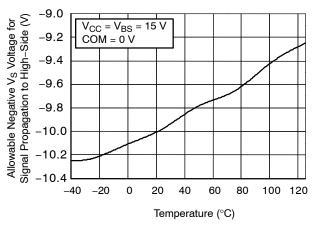


Figure 17. Allowable Negative V<sub>S</sub> Voltage for Signal Propagation to High Side vs. Temperature

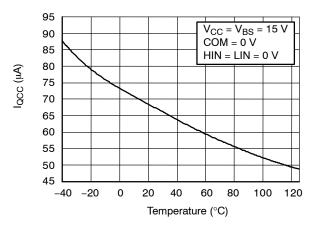
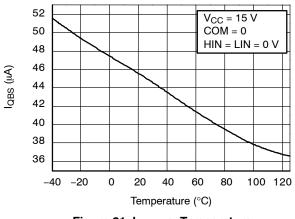
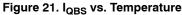
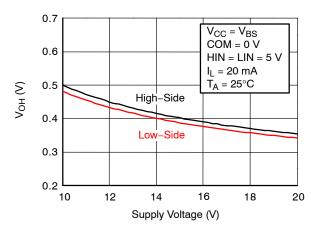


Figure 19. I<sub>QCC</sub> vs. Temperature

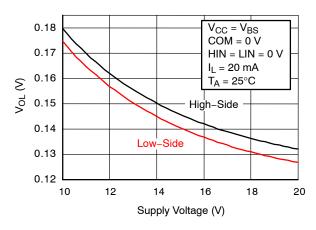




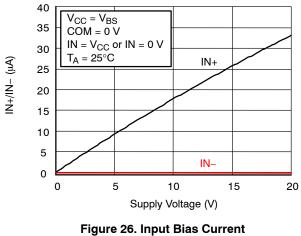
#### TYPICAL CHARACTERISTICS (continued)











vs. Supply Voltage

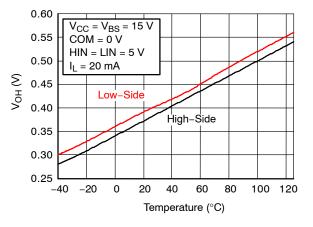


Figure 23. High–Level Output Voltage vs. Temperature

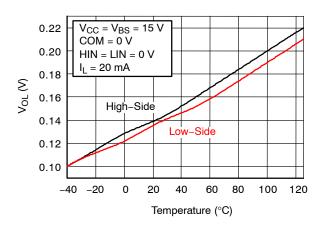
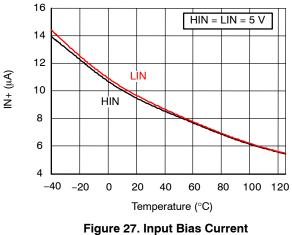


Figure 25. Low–Level Output Voltage vs. Temperature

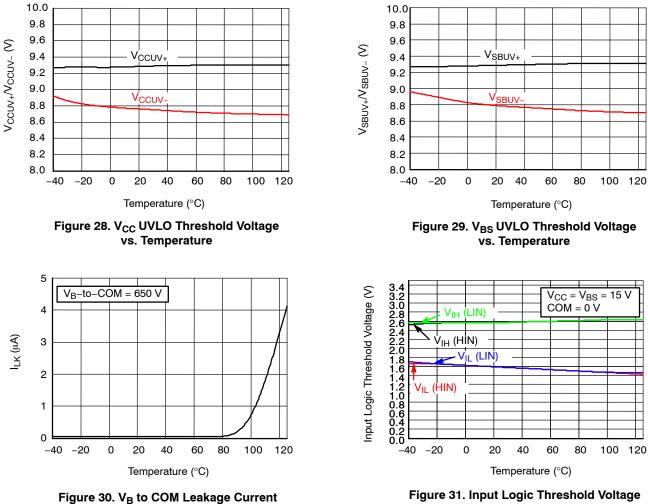


vs. Temperature

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#### TYPICAL CHARACTERISTICS (continued)



vs. Temperature

vs. Temperature

#### TYPICAL CHARACTERISTICS (continued)

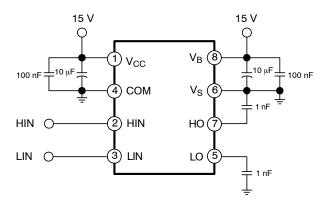


Figure 32. Switching Time Test Circuit

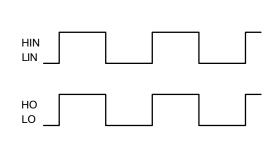


Figure 33. Input / Output Timing Diagram

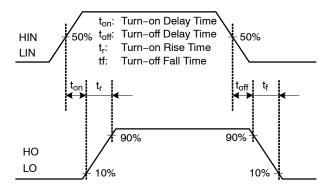


Figure 34. Switching Time Waveform Definition

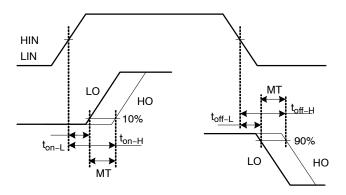
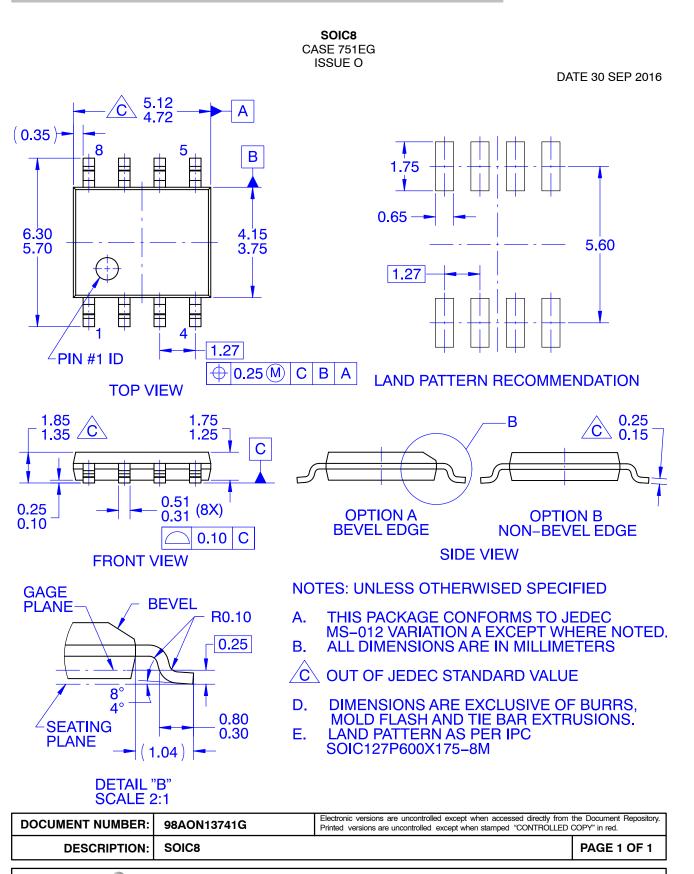


Figure 35. Delay Matching Waveform Definition

#### **ORDERING INFORMATION**

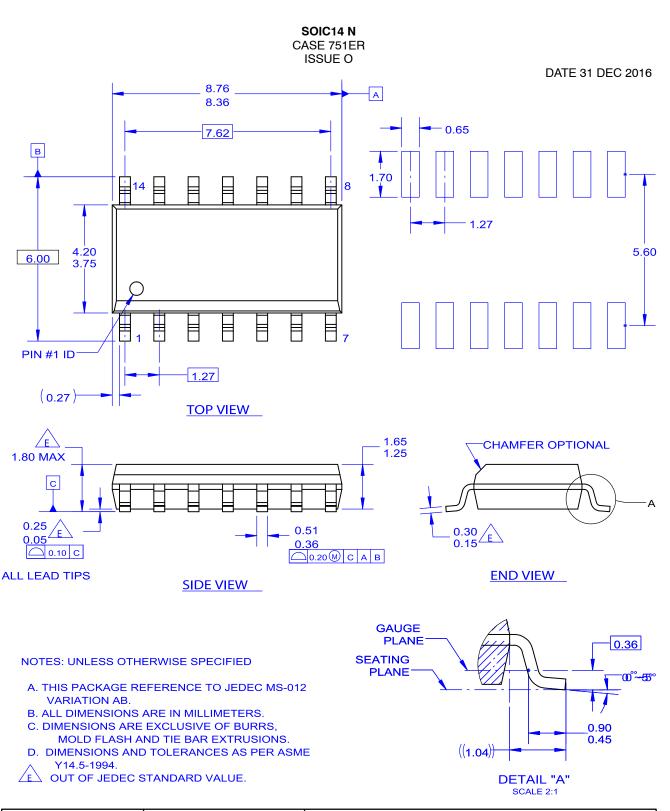
Part Number	Operating Temperature Range	Package	Shipping <sup>†</sup>
FAN7382MX (Note 5)	–40°C ∼125°C	SOIC8 (Pb–Free)	3000 / Tape & Reel
FAN7382M1X (Note 5)		SOIC14 N (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
5. These devices passed wave soldering test by JESD22A-111.



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